To our customers,

Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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RJH60D2DPP-M0

Silicon N Channel IGBT
Application: Inverter

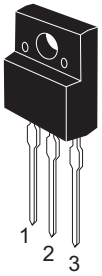
REJ03G1841-0100
Rev.1.00
Oct 14, 2009

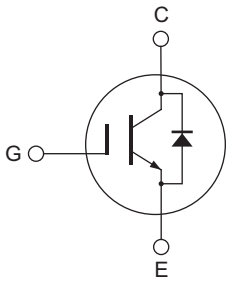
Features

- High breakdown-voltage
- Low on-voltage
- Built-in diode

Outline

RENESAS Package code: PRSS0003AF-A
(Package name: TO-220FL)





1. Gate
2. Collector
3. Emitter

Absolute Maximum Ratings

(Ta = 25°C)

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V_{CES} / V_R	600	V
Gate to emitter voltage		V_{GES}	±30	V
Collector current	Tc = 25°C	I_C	20	A
	Tc = 100°C	I_C	10	A
Collector peak current		ic(peak) Note1	40	A
Collector to emitter diode forward current		i_{DF}	10	A
Collector to emitter diode forward peak current		i_{DF}(peak) Note1	40	A
Collector dissipation		P_C Note2	22.5	W
Junction to case thermal impedance		θj-c Note2	5.5	°C/ W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	–55 to +150	°C

Notes: 1. PW ≤ 10 μs, duty cycle ≤ 1%
2. Value at Tc = 25°C

Electrical Characteristics

(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Zero gate voltage collector current / Diode reverse current	I_{CES} / I_R	—	—	100	μA	V_{CE} = 600 V, V_{GE} = 0
Gate to emitter leak current	I_{GES}	—	—	±1	μA	V_{GE} = ±30 V, V_{CE} = 0
Gate to emitter cutoff voltage	$V_{GE(off)}$	4.0	—	6.0	V	V_{CE} = 10 V, I_C = 1 mA
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	1.6	2.2	V	I_C = 10 A, V_{GE} = 15 V Note3
	$V_{CE(sat)}$	—	1.8	—	V	I_C = 20 A, V_{GE} = 15 V Note3
Input capacitance	Cies	—	430	—	pF	V_{CE} = 25 V V_{GE} = 0 f = 1 MHz
Output capacitance	Coes	—	35	—	pF	
Reveres transfer capacitance	Cres	—	15	—	pF	
Total gate charge	Qg	—	19.1	—	nC	V_{GE} = 15 V V_{CE} = 300 V I_C = 10A
Gate to emitter charge	Qge	—	3.0	—	nC	
Gate to collector charge	Qgc	—	9.0	—	nC	
Switching time	$t_{d(on)}$	—	30	—	ns	I_C = 10 A R_L = 30 Ω V_{GE} = 15 V Rg = 5 Ω
	t_r	—	30	—	ns	
	$t_{d(off)}$	—	50	—	ns	
	t_f	—	90	—	ns	
FRD Forward voltage	V_F	—	1.8	2.3	V	I_F = 10 A Note3
FRD reverse recovery time	t_{rr}	—	100	—	ns	I_F = 10 A di_F/dt = 100 A/μs

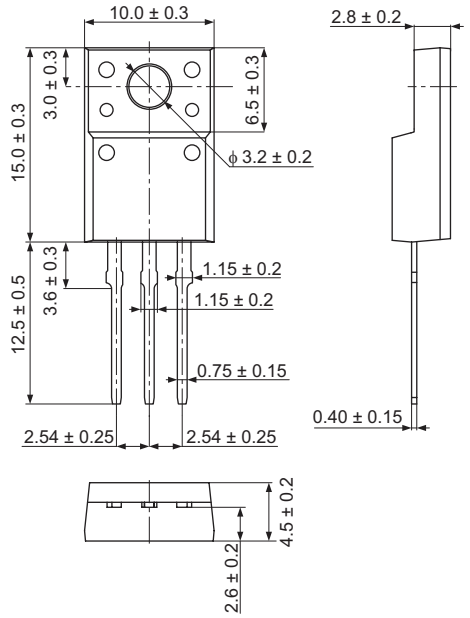
Notes: 3. Pulse test.

4. Under development — The specifications potentially be changed without notice.

Package Dimension

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
TO-220FL	—	PRSS0003AF-A	TO-220FL	1.5g

Unit: mm



Ordering Information

Part No.	Quantity	Shipping Container
RJH60D2DPP-M0-T2	1050 pcs	Box (Tube)

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